

HD74UH32

2-input OR Gate

REJ03D0203-0500Z (Previous ADE-205-018C (Z)) Rev.5.00 Feb.02.2004

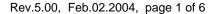
Description

The HD74UH32 is high speed CMOS two input OR gate using silicon gate CMOS process. With CMOS low power dissipation, it provides high-speed equivalent to LS-TTL series. The internal circuit of three stages construction with buffer provides wide noise margin and stable output.

Features

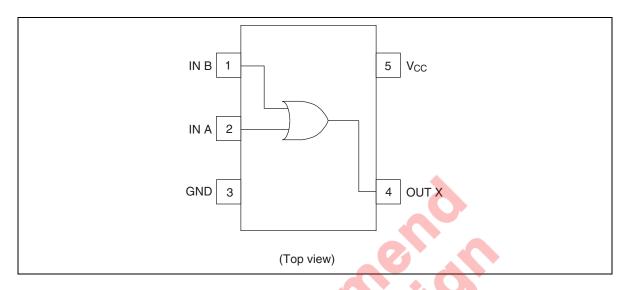
- Encapsulated in very small 5pins package of $2.9 \times 1.6 \times 1.1$ mm, the efficiency to mount on substrate is significantly improved.
- The basic gate function is lined up as Renesas uni logic series.
- Supplied on emboss taping for high-speed automatic mounting.
- Electrical characteristics equivalent to the HD74HC32 Supply voltage range: 2 to 6 V
 Operating temperature range: -40 to +85°C
- $|I_{OH}| = I_{OL} = 2 \text{ mA (min)}$
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)	
HD74UH32EL	MPAK-5 pin	MPAK-5V	_	EL (3,000 pcs/reel)	

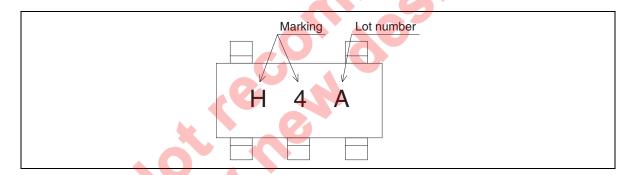




Pin Arrangement



Article Indication



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit
Supply voltage	V _{CC}	-0.5 to +7.0	V
Input voltage	V _{IN}	-0.5 to V _{CC} +0.5	V
Output voltage	V _{OUT}	-0.5 to V _{CC} +0.5	V
Input diode current	I _{IK}	±20	mA
Output diode current	I _{OK}	±20	mA
Output current	I _{OUT}	±25	mA
V _{CC} /GND current	I _{CC} , I _{GND}	±25	mA
Power dissipation	P _T	200	mW
Storage temperature	Tstg	-65 to +150	°C

HD74UH32

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	
Supply voltage	V _{CC}	2 to 6	V	
Input voltage	V _{IN}	0 to V _{CC}	V	
Output voltage	V _{OUT}	0 to V _{CC}	V	
Operating temperature	Topr	-40 to +85	°C	
Input rise/fall time	t _r , t _f	0 to 1000 (V _{CC} = 2.0 V)	ns	
		0 to 500 (V _{CC} = 4.5 V)		
		0 to 400 (V _{CC} = 6.0 V)		

Electrical Characteristics

		\mathbf{v}_{cc}	Ta =	25°C		$Ta = -40 \text{ to } 85^{\circ}C$		· .			
Item	Symbol	(V)	Min	Тур	Max	Min		Max	Unit	Test Con	ditions
Input voltage	V_{IH}	2.0	1.5	_	_	1.5			V	2)	
		4.5	3.15	_		3.15		- G	3		
		6.0	4.2	_		4.2		+21			
	V _{IL}	2.0	_	_	0.5	_		0.5	V		
		4.5	_	+c	1.35	_		1.35	_		
		6.0	70		1.8	4		1.8	_		
Output voltage	V _{OH}	2.0	1.9	2.0	=	1.9		_	V		I _{OH} = -20 μA
		4.5	4.4	4.5	4	4.4		_	_		
		6.0	5.9	6.0		5.9		_			
	10	4.5	4.18	4.31	_	4.13		_			$I_{OH} = -2 \text{ mA}$
		6.0	5.68	5.80	_	5.63		_	_		$I_{OH} = -2.6 \text{ mA}$
	VoL	2.0		0.0	0.1	_		0.1	V	$V_{IN} = V_{IL}$	I _{OL} = 20 μA
		4.5	_	0.0	0.1	_		0.1			
		6.0	_	0.0	0.1	_		0.1			
		4.5	_	0.17	0.26	_		0.33			I _{OL} = 2 mA
		6.0	_	0.18	0.26	_		0.33	_		$I_{OL} = 2.6 \text{ mA}$
Input current	I _{IN}	6.0	_	_	±0.1	_		±1.0	μΑ	$V_{IN} = V_{CC}$	or GND
Operating current	Icc	6.0	_	_	1.0			10.0		$V_{IN} = V_{CC}$	or GND

Switching Characteristics

$$(C_L = 15 \text{ pF}, t_r = t_f = 6 \text{ ns}, V_{CC} = 5 \text{ V})$$

 $Ta = 25^{\circ}C$

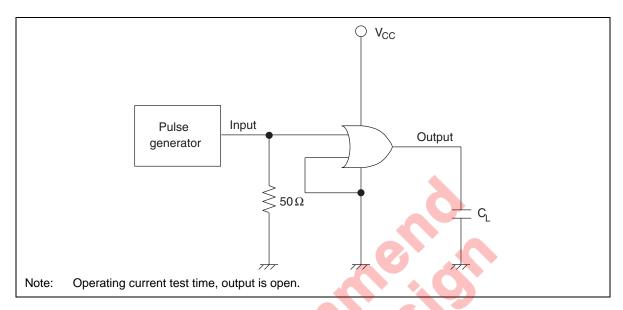
Item	Symbol	Min	Тур	Тур Мах		Test Conditions	
Output rise/fall time	t _{TLH} t _{THL}	_	5	10	ns	See Test circuit	
Propagation delay time	t _{PLH} t _{PHL}	_	7	15	ns	See Test circuit	

$$(C_L = 50 \text{ pF}, t_r = t_f = 6 \text{ ns})$$

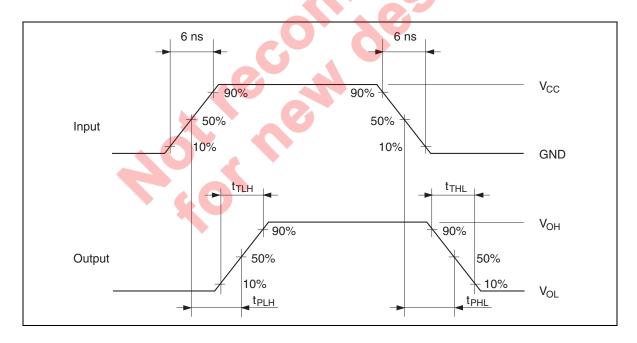
		v_{cc}	Ta =	25°C		Ta = -40	to 85°C		
Item	Symbol	(V)	Min	Тур	Max	Min	Max	Unit	Test Conditions
Output rise/fall time	t _{TLH}	2.0	_	50	125	-	155	ns	See Test circuit
	t _{THL}	4.5	_	14	25	-1	31		
		6.0	_	12	21	7	26		
Propagation delay time	t _{PLH}	2.0	_	48	100	-	125	ns	See Test circuit
	t _{PHL}	4.5	_	12	20	-0	25		
		6.0	_(9	17	_	21		
Input capacitance	C _{IN}	7	5	5	10	_	10	pF	
Equivalent capacitance	C _{PD}	4		10		_	_		

Note: C_{PD} is equivalent capacitance inside of the IC calculated from the operating current without load (see test circuit). The average operating current without load is calculated according to the expression below.

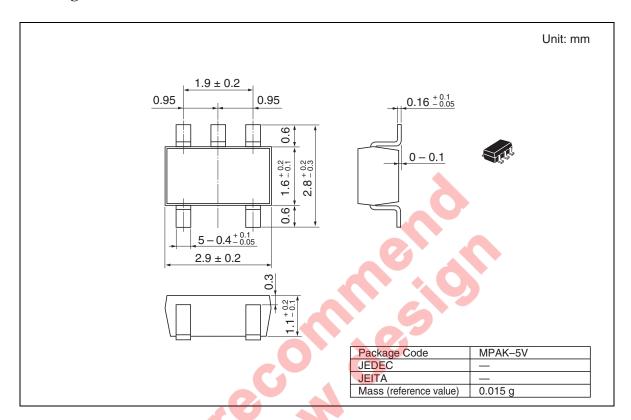
Test Circuit



Waveforms



Package Dimensions



Renesas Technology Corp. Sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

Keep safety first in your circuit designs!

1. Renesas Technology Corp. puts the maximum effort into making semiconductor products better and more reliable, but there is always the possibility that trouble may occur with them. Trouble with semiconductors may lead to personal injury, fire or property damage.

Remember to give due consideration to safety when making your circuit designs, with appropriate measures such as (i) placement of substitutive, auxiliary circuits, (ii) use of nonflammable material or (iii) prevention against any malfunction or mishap.

Notes regarding these materials

1. These materials are intended as a reference to assist our customers in the selection of the Renesas Technology Corp. product best suited to the customer's application; they do not convey any license under any intellectual property rights, or any other rights, belonging to Renesas Technology Corp. or a third party.

2. Renesas Technology Corp. assumes no responsibility for any damage, or infringement of any third-party's rights, originating in the use of any product data, diagrams, charts, programs, algorithms, or circuit application examples contained in these materials, including product data, diagrams, charts, programs and algorithms represents information on products at the time of publication of these materials, and are subject to change by Renesas Technology Corp. without notice due to product improvements or other reasons. It is therefore recommended that customers contact Renesas Technology Corp. or an authorized Renesas Technology Corp. product distributor for the latest product information before purchasing a product listed herein.

The information described here may contain technical inaccuracies or typographical errors.

Renesas Technology Corp. assumes no responsibility for any damage, liability, or other loss rising from these inaccuracies or errors.

Please also pay attention to information published by Renesas Technology Corp. by various means, including the Renesas Technology Corp. Semiconductor home page (http://www.renesas.com).

4. When using any or all of the information contained in these materials, including product data, diagrams, charts, programs, and algorithms, please be sure to evaluate all information as a total system before making a final decision on the applicability of the information and products. Renesas Technology Corp. assumes no responsibility for any damage, liability or other loss resulting from the information contained herein.

5. Renesas Technology Corp. semiconductors are not designed or manufactured for use in a device or system tha

- use.
 6. The prior written approval of Renesas Technology Corp. is necessary to reprint or reproduce in whole or in part these materials.
 7. If these products or technologies are subject to the Japanese export control restrictions, they must be exported under a license from the Japanese government and cannot be imported into a country other than the approved destination.

 Any diversion or reexport contrary to the export control laws and regulations of Japan and/or the country of destination is prohibited.

 8. Please contact Renesas Technology Corp. for further details on these materials or the products contained therein.



RENESAS SALES OFFICES

http://www.renesas.com

Renesas Technology America, Inc. 450 Holger Way, San Jose, CA 95134-1368, U.S.A Tel: <1> (408) 382-7500 Fax: <1> (408) 382-7501

Renesas Technology Europe Limited.

Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, United Kingdom Tel: <44> (1628) 585 100, Fax: <44> (1628) 585 900

Renesas Technology Europe GmbH Dornacher Str. 3, D-85622 Feldkirchen, Germany Tel: <49> (89) 380 70 0, Fax: <49> (89) 929 30 11

Renesas Technology Hong Kong Ltd. 7/F., North Tower, World Finance Centre, Harbour City, Canton Road, Hong Kong Tel: <852> 2265-6688, Fax: <852> 2375-6836

Renesas Technology Taiwan Co., Ltd. FL 10, #99, Fu-Hsing N. Rd., Taipei, Taiwan Tel: <886> (2) 2715-2888, Fax: <886> (2) 2713-2999

Renesas Technology (Shanghai) Co., Ltd. 26/F., Ruijin Building, No.205 Maoming Road (S), Shanghai 200020, China Tel: <86> (21) 6472-1001, Fax: <86> (21) 6415-2952

Renesas Technology Singapore Pte. Ltd.
1, Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632 Tel: <65> 6213-0200, Fax: <65> 6278-8001